

SEMICONDUCTOR TECHNICAL DATA

RS3AAF ~ RS3MAF

Surface Mount Fast Recovery Rectifiers Reverse Voltage - 50 to 1000 V Forward Current - 3A

FEATURES

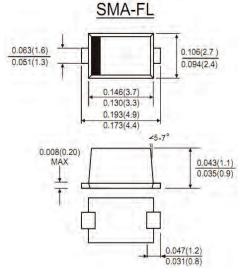
- For surface mounted applications
- Low profile package
- Glass Passivated Chip Junction
- Easy to pick and place
- Fast reverse recovery time
- Lead free in comply with EU RoHS 2011/65/EU directives

MECHANICAL DATA

· Case: SMAF

• Terminals: Solderable per MIL-STD-750, Method 2026

Approx. Weight: 27mg/0.00095oz



Absolute Maximum Ratings and Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Symbols	RS3AAF	RS3BAF	RS3DAF	RS3GAF	RS3JAF	RS3KAF	RS3MAF	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	٧
Maximum Average Forward Rectified Current at T _c = 125 °C	I _{F(AV)}	3							А
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load	I _{FSM}	105							А
Forward Surge Current (Non-repetitive) @1ms, square wave, 1 cycle, Tj=25℃	I _{FSM}	220							А
Maximum Forward Voltage at 3 A	V _F	1.3							٧
Maximum DC Reverse Current $T_a = 25 ^{\circ}\text{C}$ at Rated DC Blocking Voltage $T_a = 125 ^{\circ}\text{C}$	I _R	5 100							μA
Typical Junction Capacitance at V _R =4V, f=1MHz	C _j	32							pF
Maximum Reverse Recovery Time (1)	t _{rr}	150 250				5	500		
Typical Thermal Resistance (2)	R _{θJA} R _{θJC}	50 16							°C/W
Operating and Storage Temperature Range	T_j, T_{stg}	-55 ~ +150							°C

⁽¹⁾ Measured with $I_F = 0.5 A$, $I_R = 1 A$, $I_{rr} = 0.25 A$.

Revision No: 0

⁽ 2) P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.



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Ratings and Characteristic Curves

Fig.1 Maximum Average Forward Current Rating

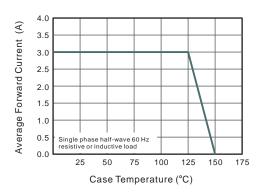


Fig.2 Typical Reverse Characteristics

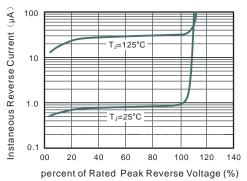


Fig.3 Typical Instaneous Forward Characteristics

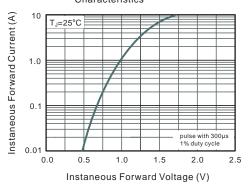


Fig.4 Typical Junction Capacitance

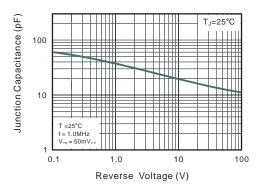


Fig.5 Maximum Non-Repetitive Peak

